

FAIRCHILD SEMICONDUCTOR®

74VHCU04 Hex Inverter

General Description

The VHCU04 is an advanced high speed CMOS Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Since the internal circuit is composed of a single stage inverter, it can be used in analog applications such as crystal oscillators. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages. July 1993 Revised February 2005

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Features

- High Speed: t_{PD} = 3.5 ns (typ) at V_{CC} = 5V
- \blacksquare Low Power Dissipation: I_{CC} = 2 μA (Max) @ T_A = 25°C
- High Noise Immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low Noise: V_{OLP} = 0.8V (Max)
- Pin and Function Compatible with 74HCU04

Ordering Code:

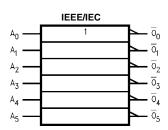
Package Number	Package Description
M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
	Number M14A M14A M14A M14D MTC14 MTC14

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

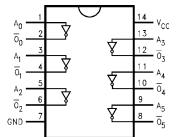
Note 1: "_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.



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Connection Diagram



Pin Descriptions

Pin Names	Description
A _n	Inputs
Ōn	Outputs

Α	ō
L	н
н	L

Absolute Maximum Ratings(Note 2)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Voltage (V _{IN})	-0.5V to +7.0V
DC Output Voltage (V _{OUT})	-0.5V to V _{CC} + 0.5V
Input Diode Current (I _{IK})	–20 mA
Output Diode Current (I _{OK})	±20 mA
DC Output Current (I _{OUT})	±25 mA
DC V _{CC} /GND Current (I _{CC})	±50 mA
Storage Temperature (T _{STG})	−65°C to +150°C
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 3)

V	Supply Voltage (V _{CC})	2.0V to +5.5V
V	Input Voltage (V _{IN})	0V to +5.5V
A	Output Voltage (V _{OUT})	0V to V _{CC}
A	Operating Temperature (T _{OPR})	-40°C to +85°C
A	Note 2: Absolute Maximum Ratings are values	,

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

260 °C Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	v _{cc}	T _A = 25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	
		(V)	Min	Тур	Max	Min	Max	01110	Conditiona	
V _{IH}	HIGH Level	2.0	1.70			1.70		v		
	Input Voltage	3.0 - 5.5	0.8 V _{CC}			0.8 V _{CC}		v		
V _{IL}	LOW Level	2.0			0.30		0.30	V		
	Input Voltage	3.0 - 5.5			0.20 V _{CC}		0.20 V _{CC}	v		
V _{OH}	HIGH Level	2.0	1.8	2.0		1.8			$V_{IN} = V_{IL}$	I _{OH} = -50 μA
	Output Voltage	3.0	2.7	3.0		2.7		V		
		4.5	4.0	4.5		4.0				
		3.0	2.58			2.48		v	$V_{IN} = GND$	I _{OH} = -4 mA
		4.5	3.94			3.80		v		I _{OH} = -8 mA
V _{OL}	LOW Level	2.0		0.0	0.2		0.2		$V_{IN} = V_{IH}$	I _{OL} = 50 μA
	Output Voltage	3.0		0.0	0.3		0.3	V		
		4.5		0.0	0.5		0.5			
		3.0			0.36		0.44	v	$V_{IN} = V_{CC}$	I _{OL} = 4 mA
		4.5			0.36		0.44	v		$I_{OL} = 8 \text{ mA}$
I _{IN}	Input Leakage Current	0 - 5.5			±0.1		±1.0	μA	$V_{IN} = 5.5V c$	or GND
I _{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V _{IN} = V _{CC} o	r GND

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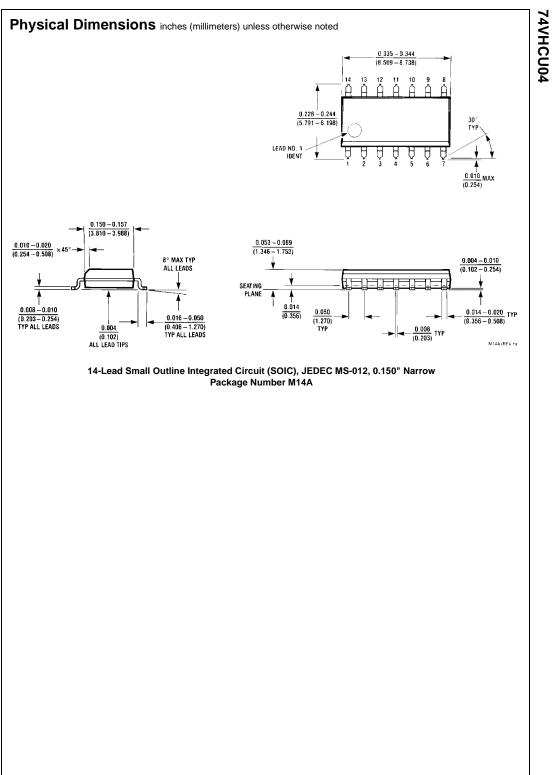
Noise Characteristics

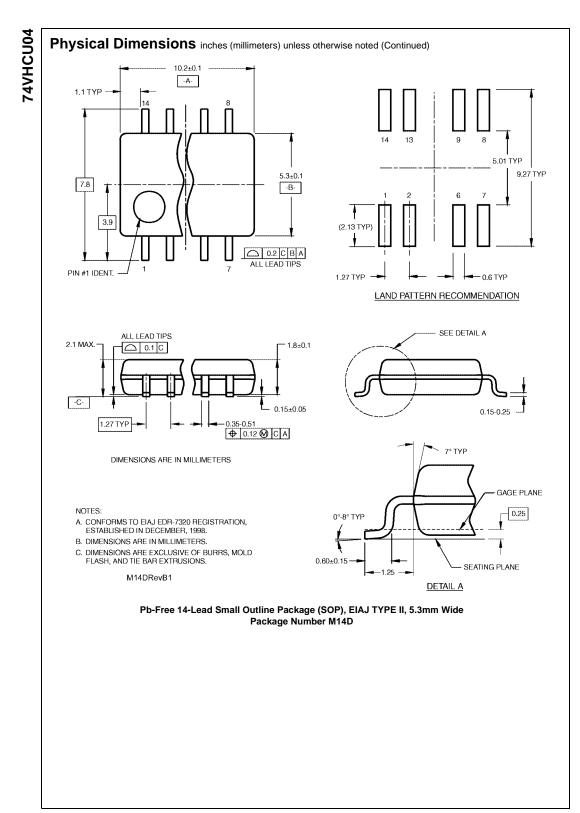
Symbol	Parameter	V _{CC}	T _A =	25°C	Units	Conditions	
Symbol		(V)	Тур	Limits		Conditions	
/ _{OLP}	Quiet Output Maximum	5.0	0.5	0.8	V	$C_L = 50 \text{ pF}$	
(Note 4)	Dynamic V _{OL}						
V _{OLV}	Quiet Output Minimum	5.0	-0.5	-0.8	V	C _L = 50 pF	
(Note 4)	Dynamic V _{OL}						
V _{IHD}	Minimum HIGH Level	5.0		4.0	V	C _L = 50 pF	
(Note 4)	Dynamic Input Voltage						
V _{ILD}	Maximum LOW Level	5.0		1.0	V	C _L = 50 pF	
(Note 4)	Dynamic Input Voltage						

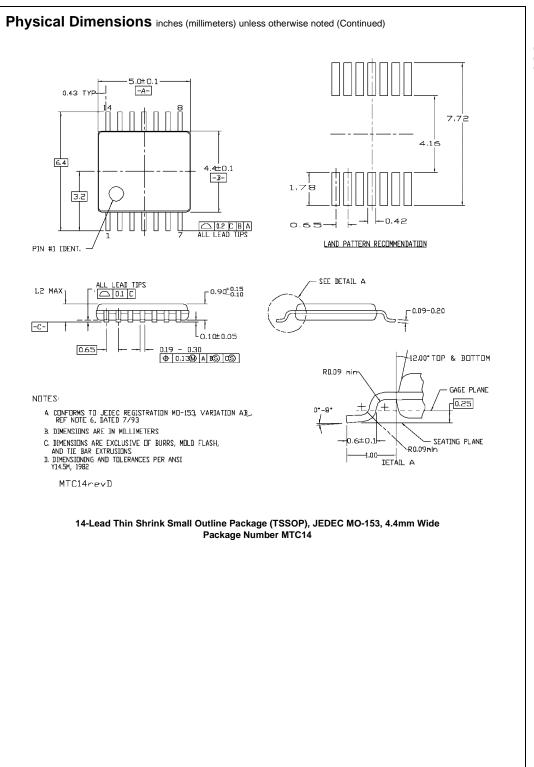
AC Electrical Characteristics

Symbol	Parameter	V _{CC}	T _A = 25°C			T _A = -40°	C to +85°C	Units	Conditions
		(V)	Min	Тур	Max	Min	Мах		Conditions
t _{PHL}	Propagation Delay	$\textbf{3.3}\pm\textbf{0.3}$		5.0	8.9	1.0	10.5	ns	C _L = 15 pF
t _{PLH}				7.5	11.4	1.0	13.0	113	$C_L = 50 \text{ pF}$
		5.0 ± 0.5		3.5	5.5	1.0	6.5	ns	C _L = 15 pF
				5.0	7.0	1.0	8.0	115	$C_L = 50 \text{ pF}$
C _{IN}	Input Capacitance			5	10		10	pF	V _{CC} = Open
C _{PD}	Power Dissipation			9				pF	(Note 5)
	Capacitance								

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + $I_{CC}/6$ (per gate).







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